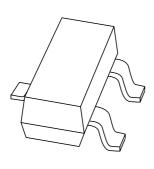
DISCRETE SEMICONDUCTORS

DATA SHEET



BCV26; BCV46
PNP Darlington transistors

Product specification Supersedes data of 1999 Apr 08 2004 Jan 13





Philips Semiconductors

PNP Darlington transistors

BCV26; **BCV46**

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 60 V)
- Very high DC current gain (min. 10000).

APPLICATIONS

• Where very high amplification is required.

DESCRIPTION

PNP Darlington transistor in a SOT23 plastic package. NPN complements: BCV27 and BCV47.

MARKING

| TYPE NUMBER | MARKING CODE ⁽¹⁾ |
|-------------|-----------------------------|
| BCV26 | FD* |
| BCV46 | FE* |

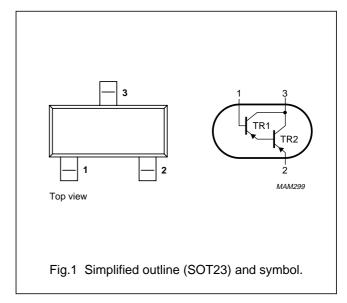
Note

* = p : Made in Hong Kong.
 * = t : Made in Malaysia.

* = W : Made in China.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | emitter |
| 3 | collector |



ORDERING INFORMATION

| TYPE | PACKAGE | | | |
|--------|-----------------------|--|-------|--|
| NUMBER | NAME DESCRIPTION VERS | | | |
| BCV26 | _ | plastic surface mounted package; 3 leads | SOT23 | |
| BCV46 | | | | |

Philips Semiconductors Product specification

PNP Darlington transistors

BCV26; BCV46

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | | | |
| | BCV26 | | _ | -40 | V |
| | BCV46 | | _ | -80 | V |
| V _{CES} | collector-emitter voltage | V _{BE} = 0 | | | |
| | BCV26 | | _ | -30 | V |
| | BCV46 | | _ | -60 | V |
| V _{EBO} | emitter-base voltage | open collector | _ | -10 | V |
| I _C | collector current (DC) | | _ | -500 | mA |
| I _{CM} | peak collector current | | _ | -800 | mA |
| I _B | base current (DC) | | _ | -100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Note

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | note 1 | 500 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

^{1.} Transistor mounted on an FR4 printed-circuit board.

Philips Semiconductors Product specification

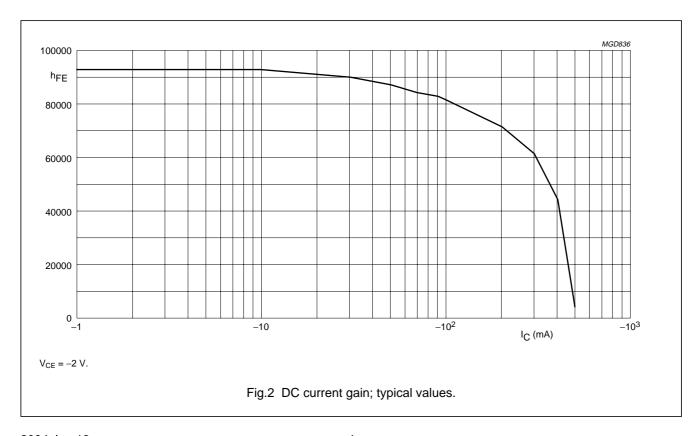
PNP Darlington transistors

BCV26; BCV46

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------------|---|-------|------|------|------|
| I _{CBO} | collector cut-off current | | | | | |
| | BCV26 | $I_E = 0$; $V_{CB} = -30 \text{ V}$ | _ | _ | -100 | nA |
| | BCV46 | $I_E = 0; V_{CB} = -60 \text{ V}$ | _ | _ | -100 | nA |
| I _{EBO} | emitter cut-off current | $I_C = 0; V_{EB} = -10 \text{ V}$ | _ | _ | -100 | nA |
| h _{FE} | DC current gain | $I_C = -1 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ (see Fig.2)}$ | | | | |
| | BCV26 | | 4000 | _ | _ | |
| | BCV46 | | 2000 | _ | _ | |
| | DC current gain | $I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ (see Fig.2)}$ | | | | |
| | BCV26 | | 10000 | _ | _ | |
| | BCV46 | | 4000 | _ | _ | |
| | DC current gain | $I_C = -100 \text{ mA}; V_{CE} = -5 \text{ V}; \text{ (see Fig.2)}$ | | | | |
| | BCV26 | | 20000 | _ | _ | |
| | BCV46 | | 10000 | _ | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = -100 \text{ mA}; I_B = -0.1 \text{ mA}$ | _ | _ | -1 | V |
| V _{BEsat} | base-emitter saturation voltage | $I_C = -100 \text{ mA}; I_B = -0.1 \text{ mA}$ | _ | _ | -1.5 | V |
| V _{BEon} | base-emitter on-state voltage | $I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}$ | _ | _ | -1.4 | V |
| f _T | transition frequency | $I_C = -30 \text{ mA}; V_{CE} = -5 \text{ V}; f = 100 \text{ MHz}$ | _ | 220 | _ | MHz |



Philips Semiconductors Product specification

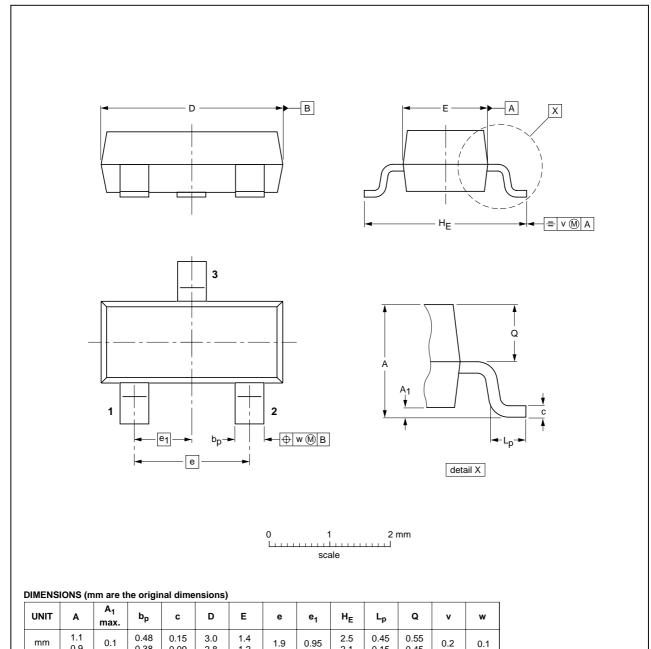
PNP Darlington transistors

BCV26; BCV46

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



| OUTLINE | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|------------|----------|------|----------|-----------------------|----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION ISSUE DATE | |
| SOT23 | | TO-236AB | | | | -97-02-28 99-09-13 |

2004 Jan 13 5

0.9

Philips Semiconductors Product specification

PNP Darlington transistors

BCV26; BCV46

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾⁽³⁾ | DEFINITION |
|-------|-------------------------------------|-------------------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| II | Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
| III | Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

Notes

- Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

DISCLAIMERS

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes in the products - including circuits, standard cells, and/or software - described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

Philips Semiconductors – a worldwide company

Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2004

SCA76

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

R75/05/pp7

Date of release: 2004 Jan 13

Document order number: 9397 750 12401

Let's make things better.

Philips Semiconductors



